# VS-U5FH30BA60



## FRED Pt<sup>®</sup> Gen 5 Ultrafast Single Phase Bridge (Power Modules), 600 V, 30 A



www.vishay.com

PRIMARY CHARACTERISTICS							
V <sub>RRM</sub>	600 V						
I <sub>O</sub> at T <sub>C</sub> = 131 °C	30 A						
V <sub>F</sub> (typical) at 30 A, per diode	1.6 V						
t <sub>rr</sub> (typical) at 30 A, per diode	63 ns						
Туре	Modules - Bridge, Hyperfast						
Package	SOT-227						
Circuit configuration	Single phase bridge						

### **FEATURES**

- Ultrafast and optimized Q<sub>rr</sub>
- · Best in class forward voltage drop and switching losses trade off



COMPLIANT

- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- · Electrically isolated base plate
- Large creepage distance between terminal
- Simplified mechanical designs, rapid assembly
- Designed and qualified for industrial level
- UL approved file E78996
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

Featuring a unique combination of low conduction and switching losses, the VS-U5FH30BA60 is the right choice for high frequency converters, both soft switched / resonant. The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters, and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
1		30	А				
I <sub>O</sub>	T <sub>C</sub>	131	°C				
1	50 Hz	290	•				
IFSM	60 Hz	305	A				
l <sup>2</sup> t	50 Hz	424	– A <sup>2</sup> s				
1-1	60 Hz	387	A-S				
V <sub>RRM</sub>		650	V				
TJ		-55 to +175	°C				

### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V						
VS-U5FH30BA60	60	600	600						

Revision: 22-Apr-2024 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000

Document Number: 96937



www.vishay.com

## Vishay Semiconductors

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA	600	-	-			
Forward voltage	M	I <sub>F</sub> = 30 A	-	1.6	2.1	V		
Forward voltage	V <sub>FM</sub>	I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.26	-			
		V <sub>R</sub> = 600 V	-	0.1	30			
Reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 125 °C, V <sub>R</sub> = 600 V	-	14	-	μA		
		T <sub>J</sub> = 150 °C, V <sub>R</sub> = 600 V	-	53	-			
RMS isolation voltage base plate	VISOL	f = 50 Hz, any terminal to case, t = 1 min	2500	-	-	V		

FORWARD CONDUCTION							
PARAMETER	SYMBOL	. TEST CONDITIONS VALUES UNIT					
Maximum DC output current	1	Resistive or ind	luctive load		30	А	
at case temperature	Ι <sub>Ο</sub>				131	°C	
		t = 10 ms	No voltage		291		
Maximum peak, one-cycle	1	t = 8.3 ms	reapplied	- Initial T <sub>J</sub> = 25 °C	305	А	
non-repetitive forward current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		245		
		t = 8.3 ms	reapplied		256	1	
		t = 10 ms	No voltage		424	A <sup>2</sup> s	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 8.3 ms	reapplied		387		
Maximum r-t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		300		
		t = 8.3 ms	reapplied		274		
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	$I^{2}t$ for time $t_{x} =$	$I_2 \sqrt{t} \; x \; \sqrt{t_x};  0.1 \leq t_x \leq 1$	0 ms, $V_{RRM} = 0 V$	4244	kA²√s	
Low level of threshold voltage, per leg	V <sub>F(T0)1</sub>	0.96				V	
Low level value of forward slope resistance	r <sub>f1</sub>	$(16.7 \% \text{ x } \pi \text{ x } I_{F(AV)}) < I < \pi \text{ x } I_{F(AV)}, T_J = T_J \text{ maximum}$ $25.02 \text{ m}\Omega$				mΩ	
High level of threshold voltage, per leg	V <sub>F(T0)2</sub>				1.31	V	
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ $23.71 \text{ m}\Omega$				mΩ	
Maximum forward voltage, per diode	V <sub>FM</sub>	I <sub>F</sub> = 30 A			2.1	V	

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST	CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Poverse recovery time	+	T <sub>J</sub> = 25 °C		-	57	-	20	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C	$I_{\rm F} = 30  \text{A},$	-	62	-	ns	
Deals receiver a current		T <sub>J</sub> = 25 °C		-	12	-	٨	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	di <sub>F</sub> /dt = 1000 A/µs, V <sub>B</sub> = 400 V	-	25	-	A	
Reverse recovery charge	0	0	$T_J = 25 \ ^\circ C$		-	0.3	-	
Reverse recovery charge Q <sub>rr</sub>		T <sub>J</sub> = 125 °C		-	0.9	-	μC	
Junction capacitance	CT	V <sub>R</sub> = 600 V, f :	= 1 MHz	-	29	-	pF	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance junction to case, per diode	R <sub>thJC</sub>		-	-	1.39	°C/W		
Thermal resistance case to heatsink, per module	R <sub>thCS</sub>	Flat, greased, surface	-	0.05	-	C/W		
Weight			-	30	-	g		
Mounting torque		Torque per diode	-	-	1.1 (9.7)	Nm (lbf.in)		
Mounting torque		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)		
Case style				S	DT-227			

Revision: 22-Apr-2024

Document Number: 96937

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





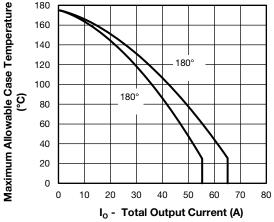


Fig. 1 - Current Rating Characteristics

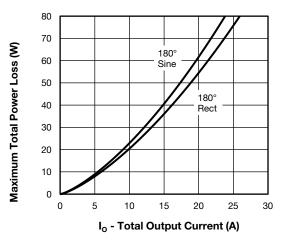


Fig. 2 - Total Power Loss Characteristics

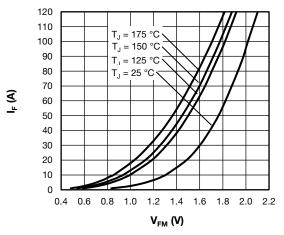


Fig. 3 - Typical Forward Voltage Drop Characteristics

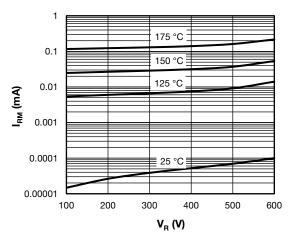
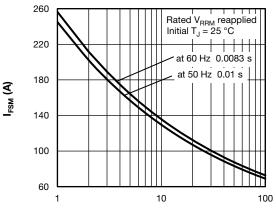


Fig. 4 - Typical Values of Reverse Current



Number of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 5 - Non-Repetitive Peak Forward Surge Current vs. Number Pulses

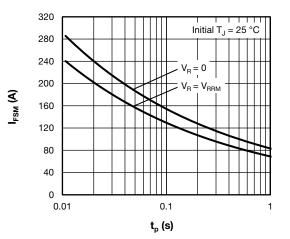


Fig. 6 - Non-Repetitive peak Forward Surge Current vs. Pulse Duration

Revision: 22-Apr-2024

3

Document Number: 96937

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



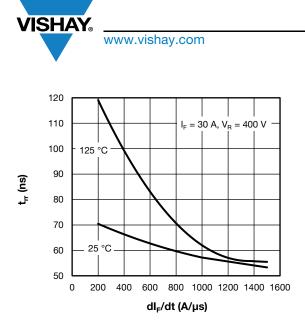


Fig. 7 - Diode Reverse Recovery Time vs. dl<sub>F</sub>dt

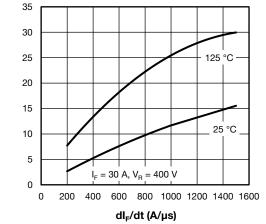


Fig. 8 - Diode Reverse Recovery Current vs. dl<sub>F</sub>dt

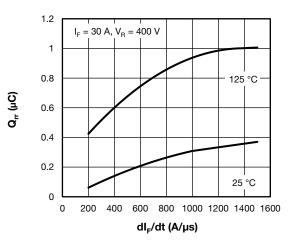


Fig. 9 - Diode Reverse Recovery Charge vs. dl<sub>F</sub>dt

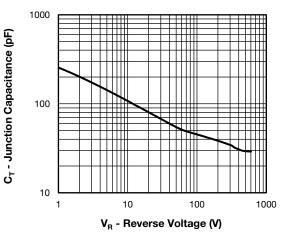


Fig. 10 - Junction Capacitance

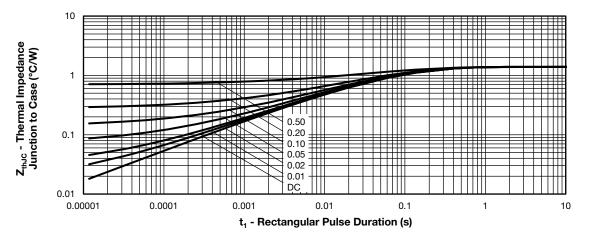


Fig. 11 - Maximum Thermal Impedance Junction to Case

 Revision: 22-Apr-2024
 Document Number: 96937

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 DiodesEurope@vishay.com

 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

I<sub>rr</sub> (A)



### **ORDERING INFORMATION TABLE**

Device code	vs-	U5F	н	30	В	Α	60
		2	3	4	5	6	7
	1 .	- Visł	nay Sem	niconduo	ctors pr	oduct	
	<b>2</b> - U5F = Gen 5 FRED $Pt^{(B)}$ family						
	3 -	- H = Ultrafast FRED Pt <sup>®</sup> diode					
	4	- Cur	rent rati	ng per r	nodule	(30 = 30	) A)
	5 -	• B =	circuit o	configur	ation (S	ingle pł	nase bri
	6	- Pac	kage in	dicator	(SOT-22	27 stand	dard ins
	7	- Volt	tage rati	ng (60 =	= 600 V)		

CIRCUIT CONFIGURATION							
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING					
Single phase bridge	В	4 (AC) 3 (-) $\downarrow$ (AC) 3 (-) $\downarrow$ (AC) 3 (-) $\downarrow$ (AC) 4 $\downarrow$ (AC) 3 (-) $\downarrow$ (AC) 4 $\downarrow$ (AC) 3 (-) $\downarrow$ (AC) 4 $\downarrow$ (AC) 3 $\downarrow$ (AC) 3					

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95423						
Packaging information	www.vishay.com/doc?95425					



SOT-227 Generation 2

#### **DIMENSIONS** in millimeters (inches)



#### Note

• Controlling dimension: millimeter



Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1